

UNISONIC TECHNOLOGIES CO., LTD

15N50K-MT Power MOSFET

15A, 500V N-CHANNEL POWER MOSFET

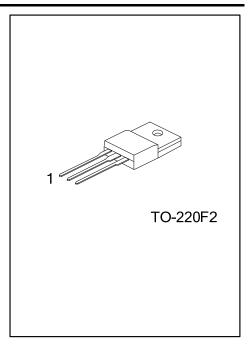
DESCRIPTION

The UTC **15N50K-MT** is an N-channel mode power MOSFET using UTC's advanced technology to provide customers with planar stripe and DMOS technology. This technology allows a minimum on-state resistance and superior switching performance. It also can withstand high energy pulse in the avalanche and commutation mode.

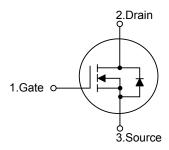
The UTC **15N50K-MT** is generally applied in high efficiency switch mode power supplies.



- * $R_{DS(ON)}$ < 0.36 Ω @ V_{GS} = 10 V, I_{D} = 7.5 A
- * High Switching Speed



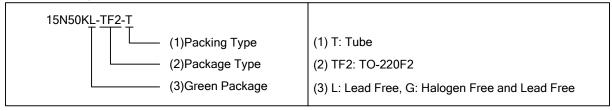
■ SYMBOL



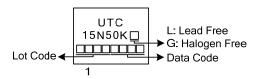
ORDERING INFORMATION

Ordering Number		Dookogo	Pin Assignment			Dooking
Lead Free	Halogen Free	Package	1	2	3	Packing
15N50KL-TF2-T	15N50KG-TF2-T	TO-220F2	G	D	S	Tube

Note: Pin Assignment: G: Gate D: Drain S: Source



MARKING



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15N50K-MT Power MOSFET

■ ABSOLUTE MAXIMUM RATINGS (T_C=25°C, unless otherwise specified.) (Note 5)

PARAMETER			SYMBOL	RATINGS	UNIT	
Drain to Source Voltage		V_{DSS}	500	V		
Gate-Source Voltage		V_{GSS}	±30	V		
IDrain Current	Continuous	T _C =25°C	I _D	15	Α	
	Pulsed (Note 2)		I _{DM}	60	Α	
Avalanche Current (Note 2)		I _{AR}	15	Α		
Avalanche Energy Single Pulsed (Note 3)		E _{AS}	800	mJ		
Peak Diode Recovery dv/dt (Note 4)		dv/dt	15	V/ns		
Power Dissipation (T _C =25°C)		Б	52	W		
Derate above 25°C		P_D	0.416	W/°C		
Junction Temperature		TJ	+150	°C		
Storage Temperature		T _{STG}	-55~+150	°C		

Notes: 1. Absolute maximum ratings are those values beyond which the device could be permanently damaged. Absolute maximum ratings are stress ratings only and functional device operation is not implied.

- 2. Repetitive Rating; Pulse width limited by maximum junction temperature
- 3. L=7.11mH, I_{AS} =15A. V_{DD} =50V, R_{G} =25 Ω , Starting T_{J} =25 $^{\circ}$ C
- 4. I_{SD}≤15A, di/dt≤200A/μs, V_{DD}≤BV_{DSS}, Starting T_J=25°C
- 5. Drain current limited by maximum junction temperature

■ THERMAL DATA

PARAMETER	SYMBOL	RATINGS	UNIT	
Junction to Ambient	θ_{JA}	62.5	°C/W	
Junction to Case	θ_{JC}	2.4	°C/W	

■ ELECTRICAL CHARACTERISTICS

SYMBOL	TEST CONDITIONS		TYP	MAX	UNIT				
OFF CHARACTERISTICS									
BV_{DSS}	I_D =250 μ A, V_{GS} =0V, T_J =25 $^{\circ}$ C	500			V				
$\Delta BV_{DSS}/\Delta T_{J}$	Reference to 25°C I _s =250µA		0.5		V/°C				
	Treference to 25 G, ID-250µA		0.0		V/ C				
Ince	V _{DS} =500V, V _{GS} =0V			1	μΑ				
1033	V _{DS} =400V, V _{GS} =0V, T _J =125°C			10	μΑ				
loos	V _{GS} =+30V, V _{DS} =0V			+100	nΑ				
IGSS	V_{GS} =-30V , V_{DS} =0V			-100	nA				
ON CHARACTERISTICS									
$V_{GS(TH)}$	$V_{GS}=V_{DS}$, $I_D=250\mu A$			4.0	V				
R _{DS(ON)}	V _{GS} =10V, I _D =7.5A		0.27	0.36	Ω				
C _{ISS}	V _{DS} =25V, V _{GS} =0V, f=1.0MHz		970		pF				
Coss			210		pF				
C _{RSS}			11		pF				
_									
$t_{D(ON)}$			91		ns				
t _R	V_{DS} =30V, I_{D} =0.5A, R_{G} =25 Ω		147		ns				
t _{D(OFF)}	(Note 1, 2)		258		ns				
t⊧			156		ns				
Q_{G}	\/ -10\/ \/ -50\/ -1.2A		47.3		nC				
Q_GS			13		nC				
Q_GD	(Note 1, 2)		13.2		nC				
CHARACTER	ISTICS								
Is				15	Α				
I _{SM}				60	Α				
V_{SD}	I _{SD} =15A, V _{GS} =0V			1.4	V				
	BV _{DSS} $\Delta BV_{DSS}/\Delta T_J$ IDSS IGSS VGS(TH) RDS(ON) CISS COSS CRSS tD(ON) tR tD(OFF) tF QG QGS QGD CHARACTER ISM	$ \begin{array}{c ccccccccccccccccccccccccccccccccccc$	$ \begin{array}{c ccccccccccccccccccccccccccccccccccc$	$\begin{array}{c ccccccccccccccccccccccccccccccccccc$	$\begin{array}{c ccccccccccccccccccccccccccccccccccc$				

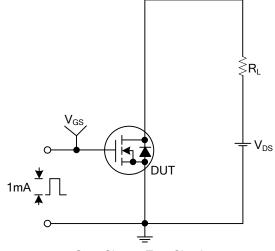
Notes: 1. Pulse Test: Pulse width≤300µs; Duty Cycle≤2%

2. Essentially Independent of Operating Temperature Typical Characteristics

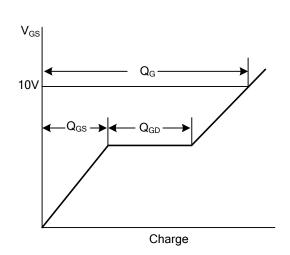


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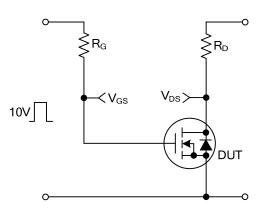
■ TEST CIRCUITS AND WAVEFORMS



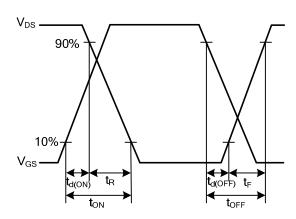
Gate Charge Test Circuit



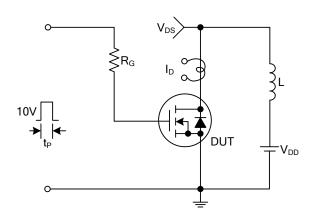
Gate Charge Waveforms



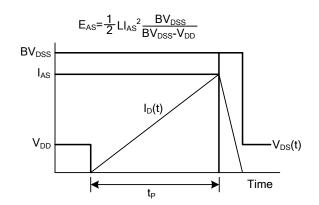
Resistive Switching Test Circuit



Resistive Switching Waveforms

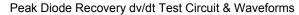


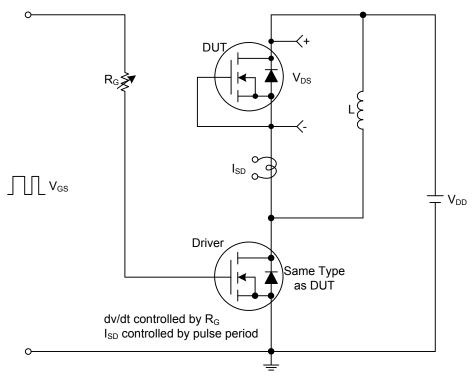
Unclamped Inductive Switching Test Circuit

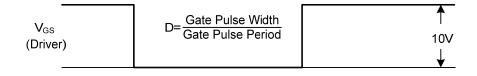


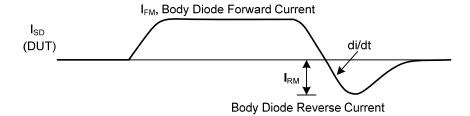
Unclamped Inductive Switching Waveforms

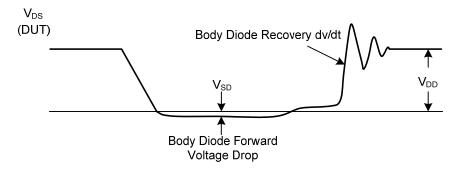
■ TEST CIRCUITS AND WAVEFORMS(Cont.)



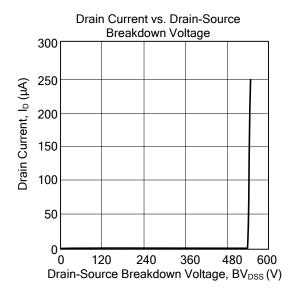


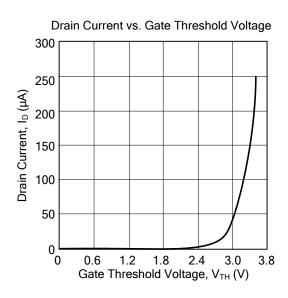


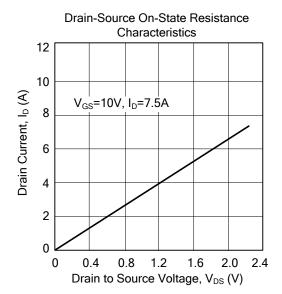


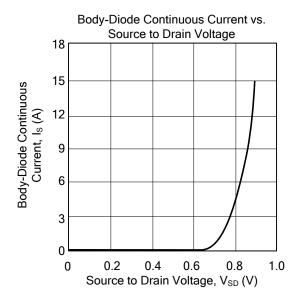


■ TYPICAL CHARACTERISTICS









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